

Role of Phenothiazine/Phenoxazine Donor in Solid Ionic Conductors for Efficient Solid State Dye Sensitized Solar Cells

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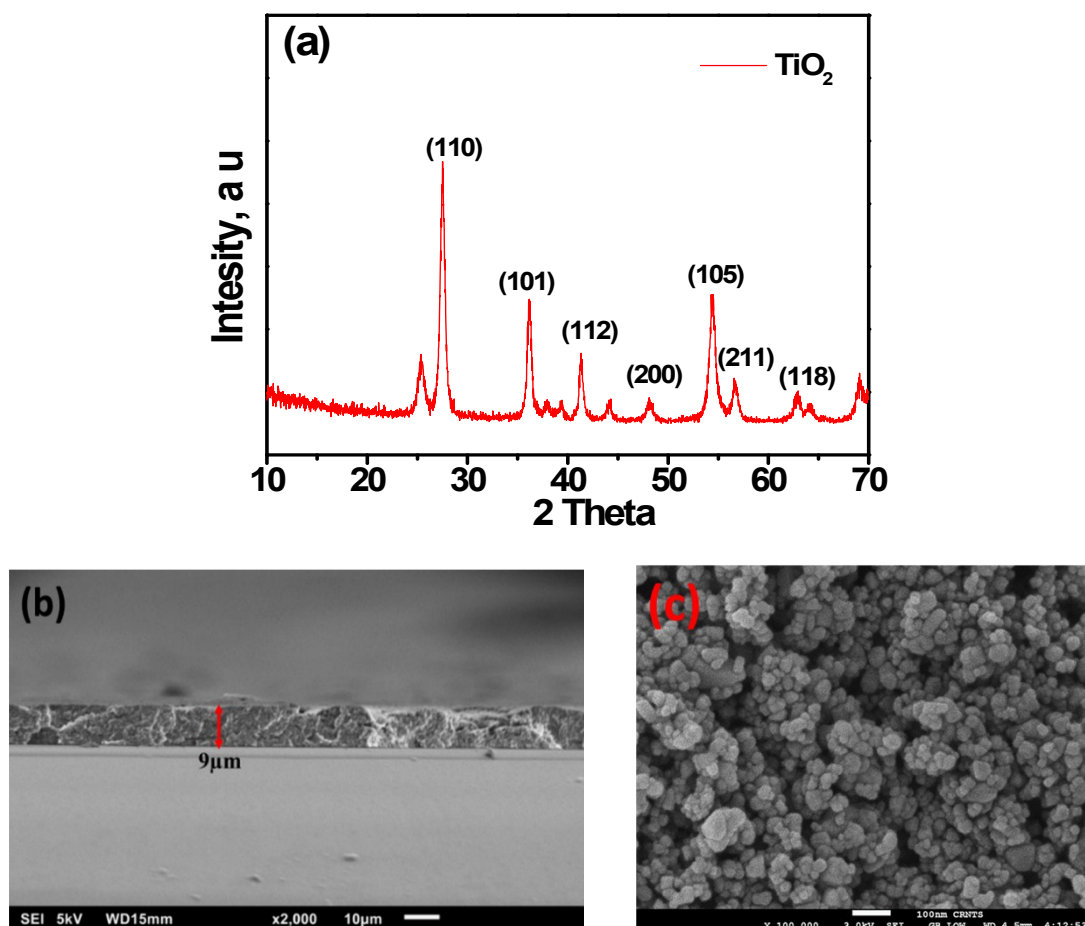
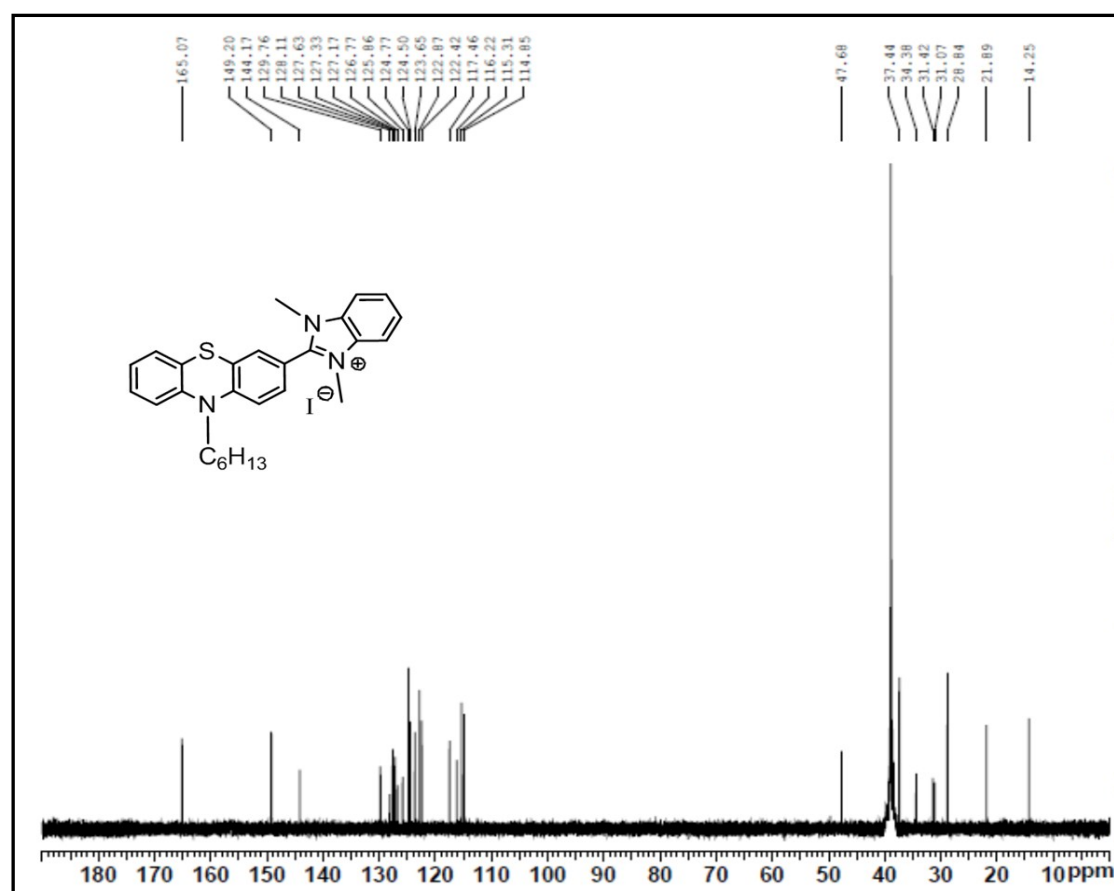
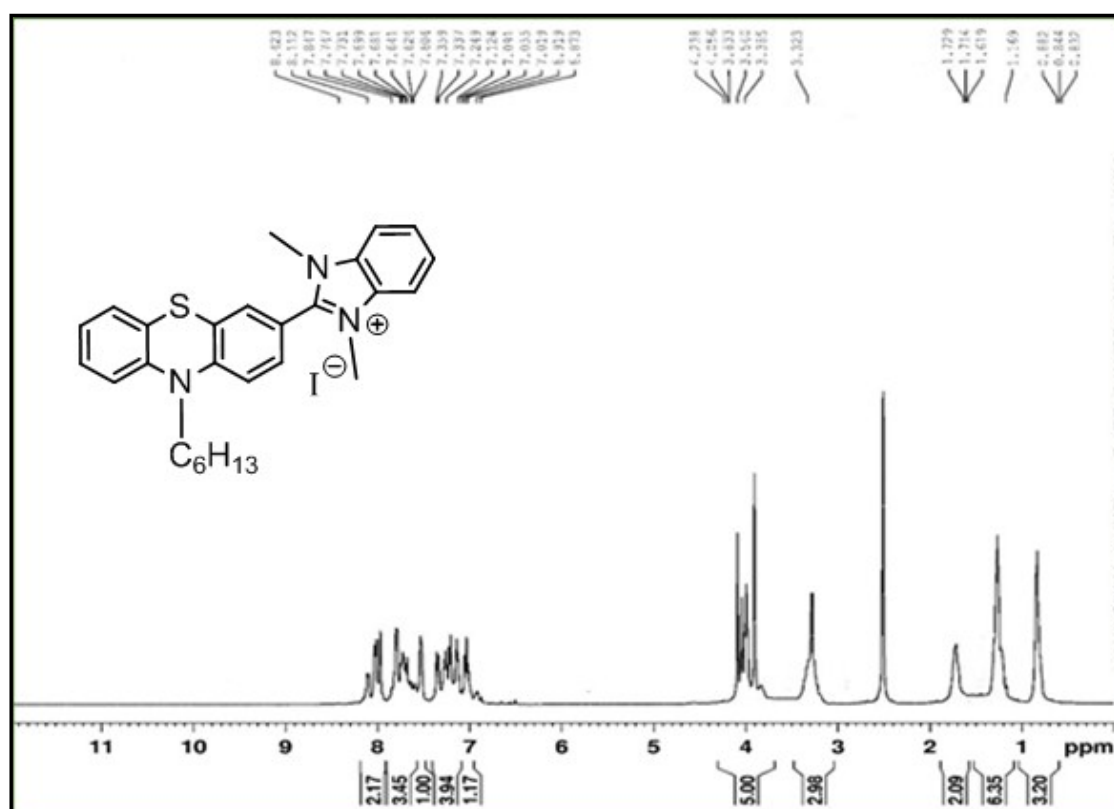


Fig. S1. (a) XRD pattern, (b) SEM image of cross section and (c) SEM image top view for TiO_2 Photoanode

We have used anatase nanoporous TiO_2 particles. Structural characterizations of TiO_2 particles were carried out by using XRD. Above **Fig. S1(a)** shows the X-Ray diffraction pattern of the TiO_2 nanoparticles showing the presence of pure crystalline anatase phase along with sign of little rutile domain. The peaks in the diffraction pattern can be attributed to the (110), (101), (112), (200), (105), (211) and (118) planes respectively.



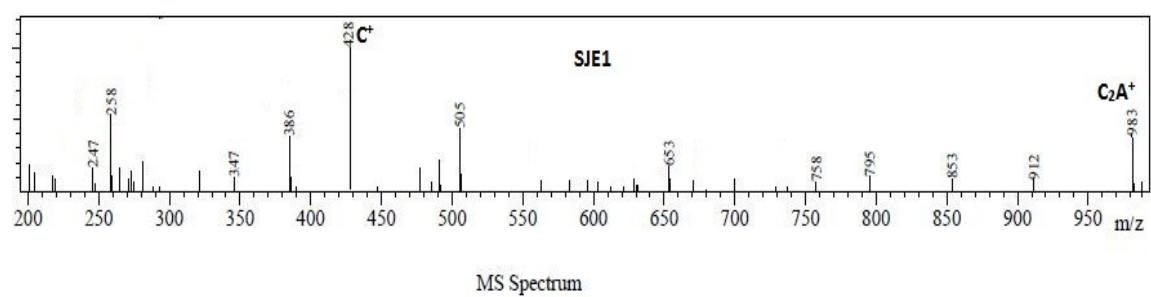
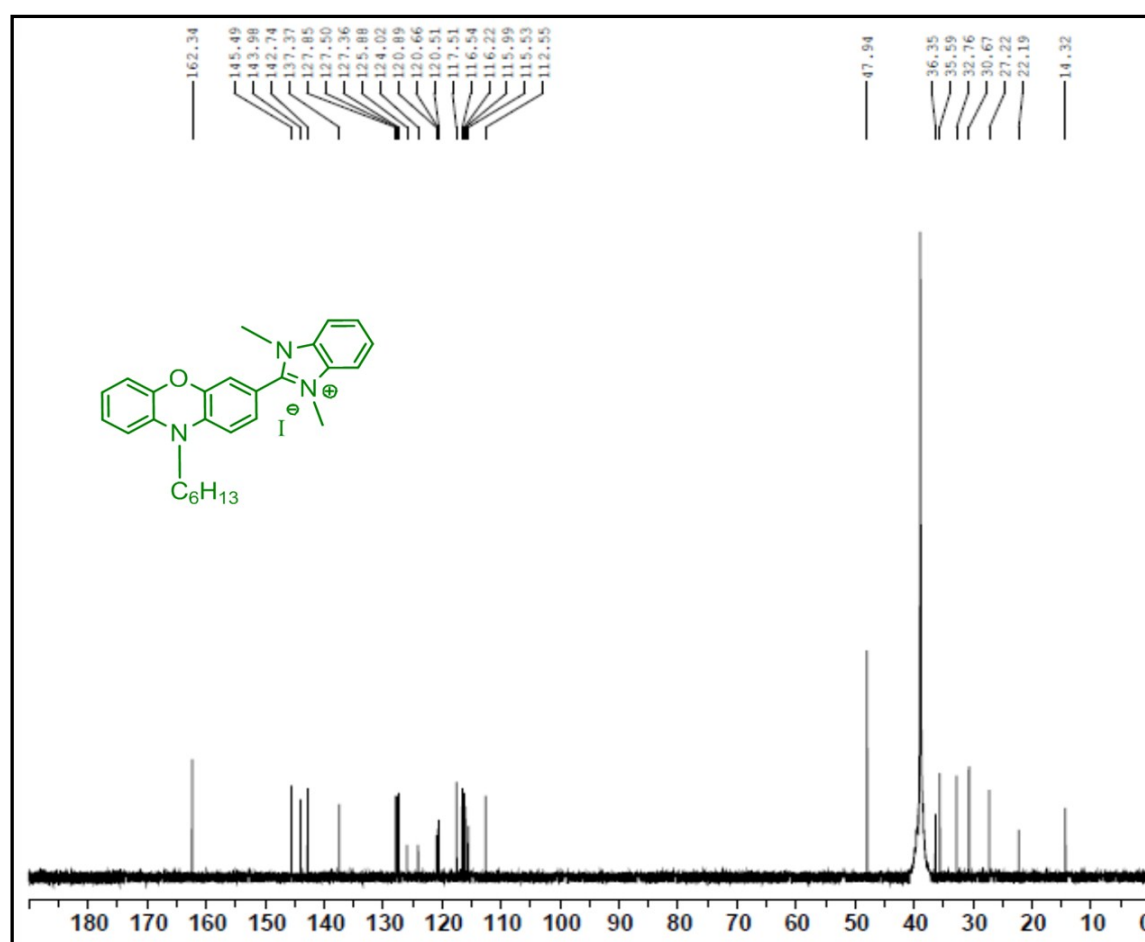
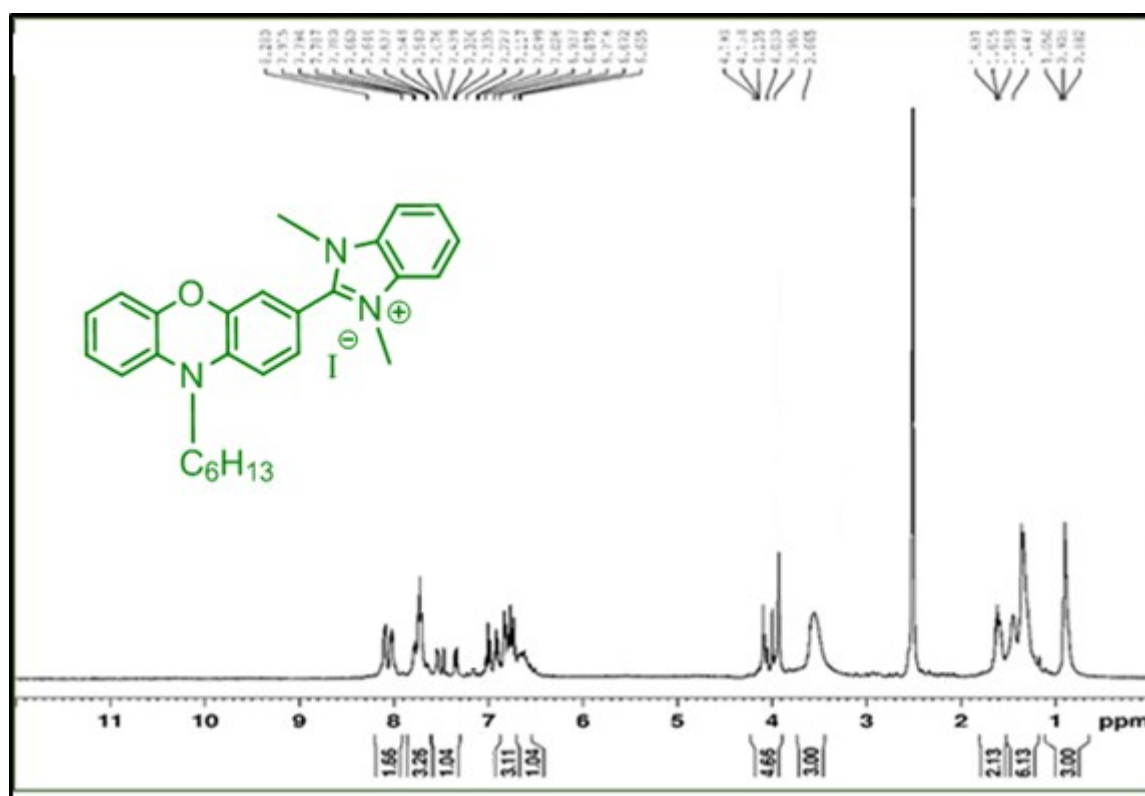


Fig. S2. 1H -NMR and ^{13}C -NMR and MS spectra of SJE 1



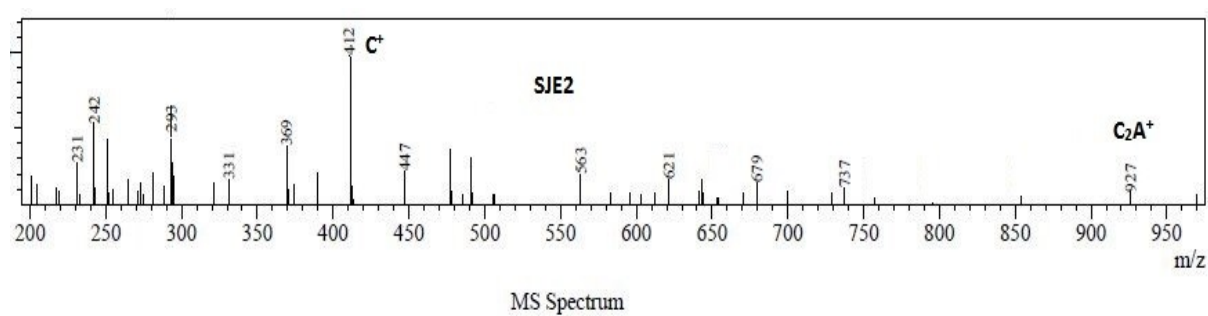
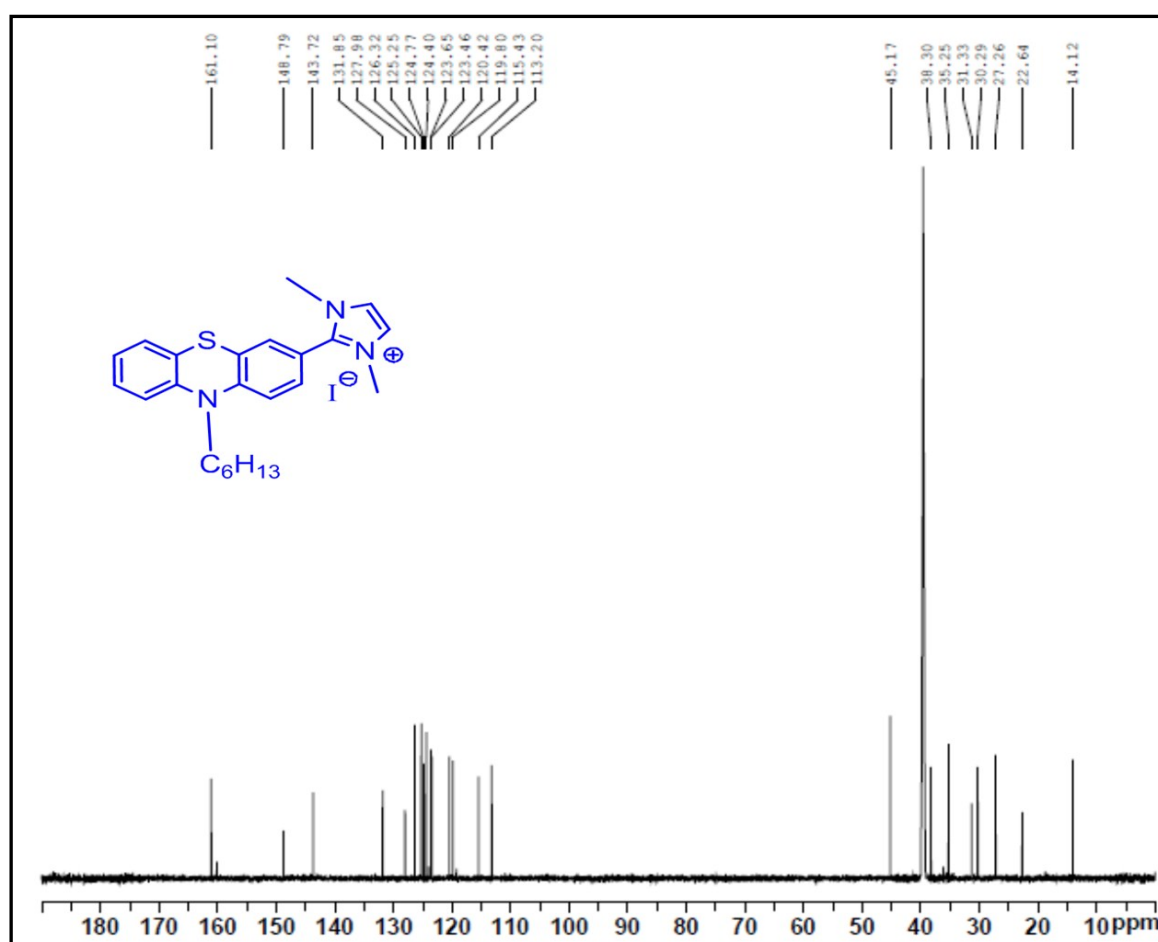
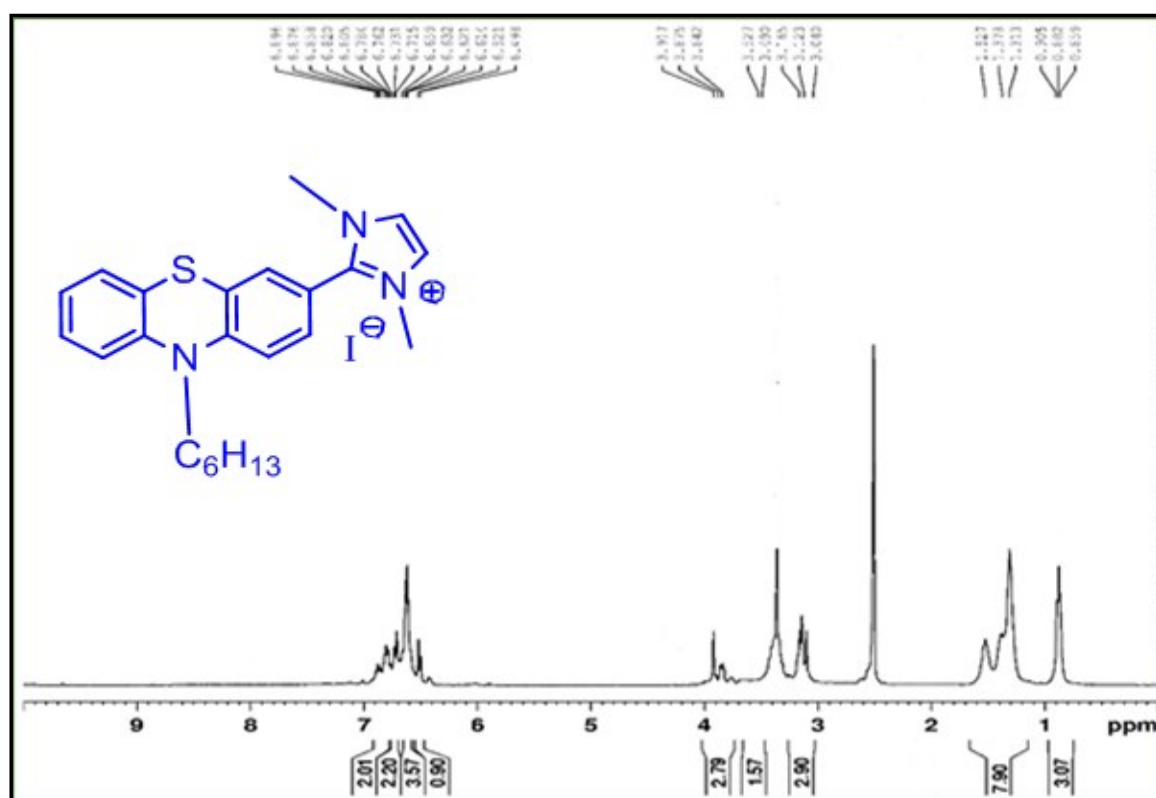


Fig. S3. 1H -NMR and ^{13}C -NMR and MS spectra of SJE 2



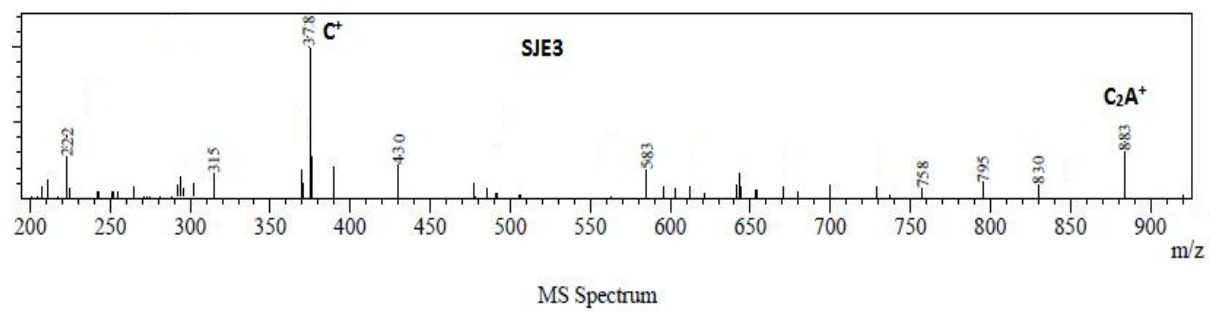
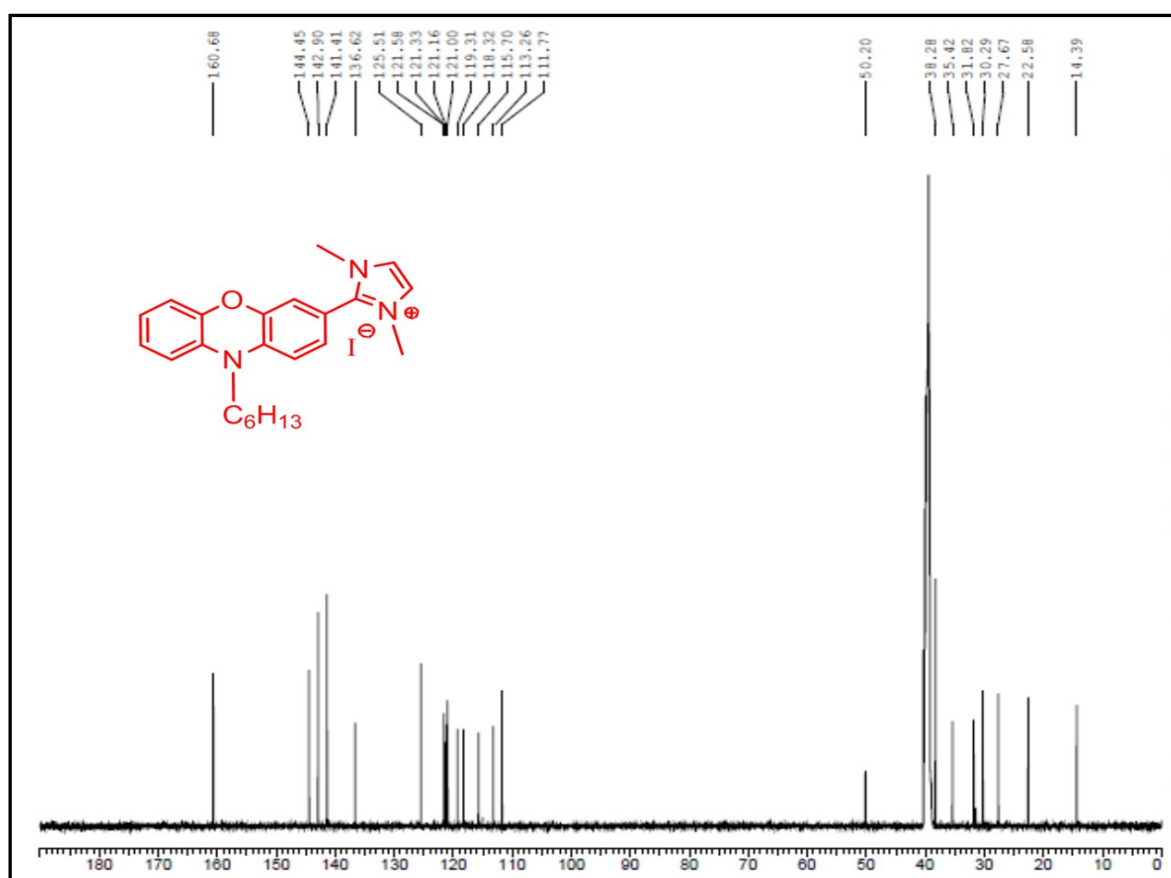
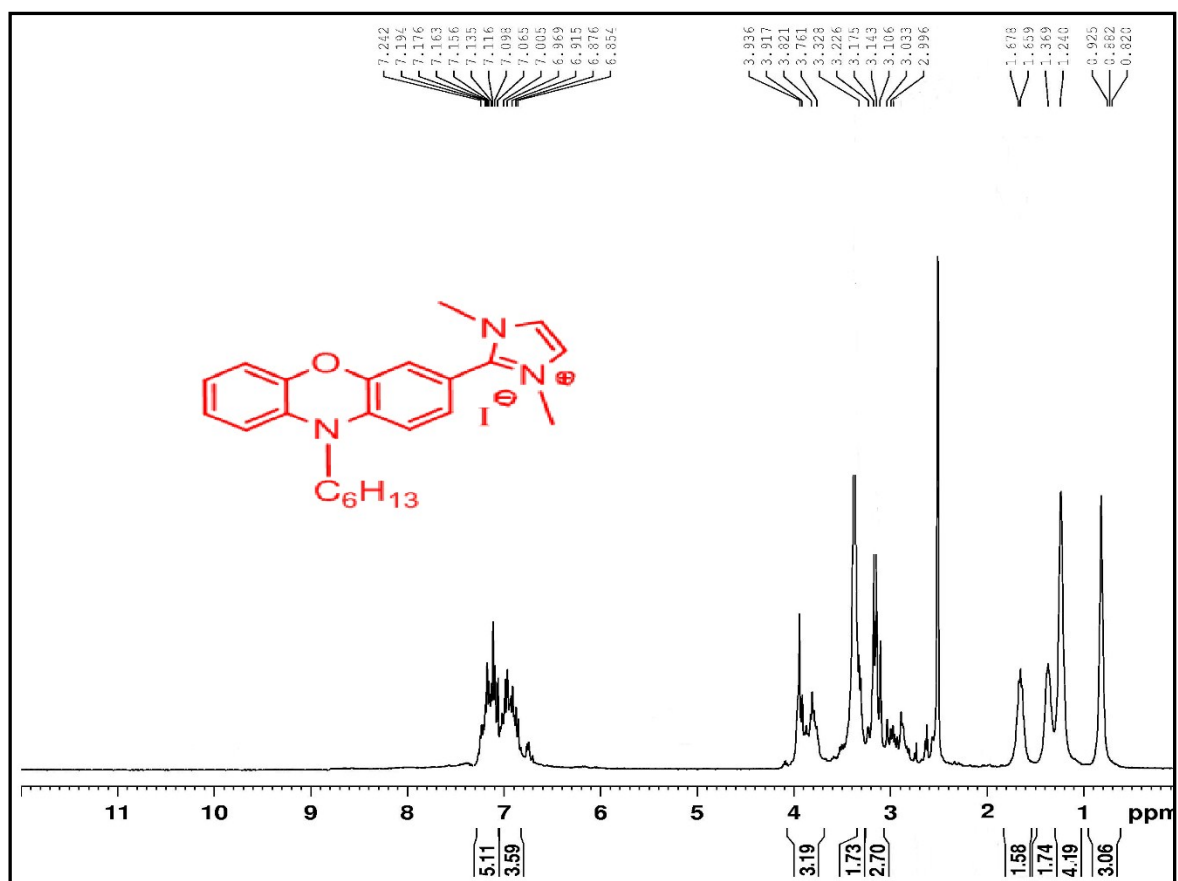


Fig. S4. 1H -NMR and ^{13}C -NMR and MS spectra of SJE 3



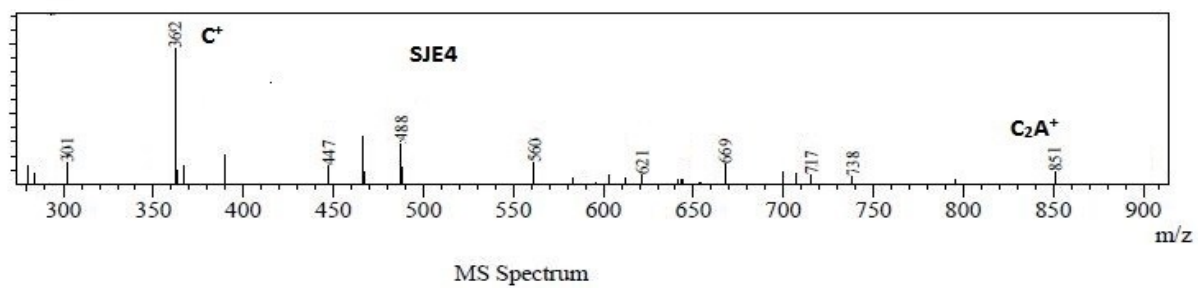


Fig. S5. 1H -NMR and ^{13}C -NMR and MS spectra of SJE 4

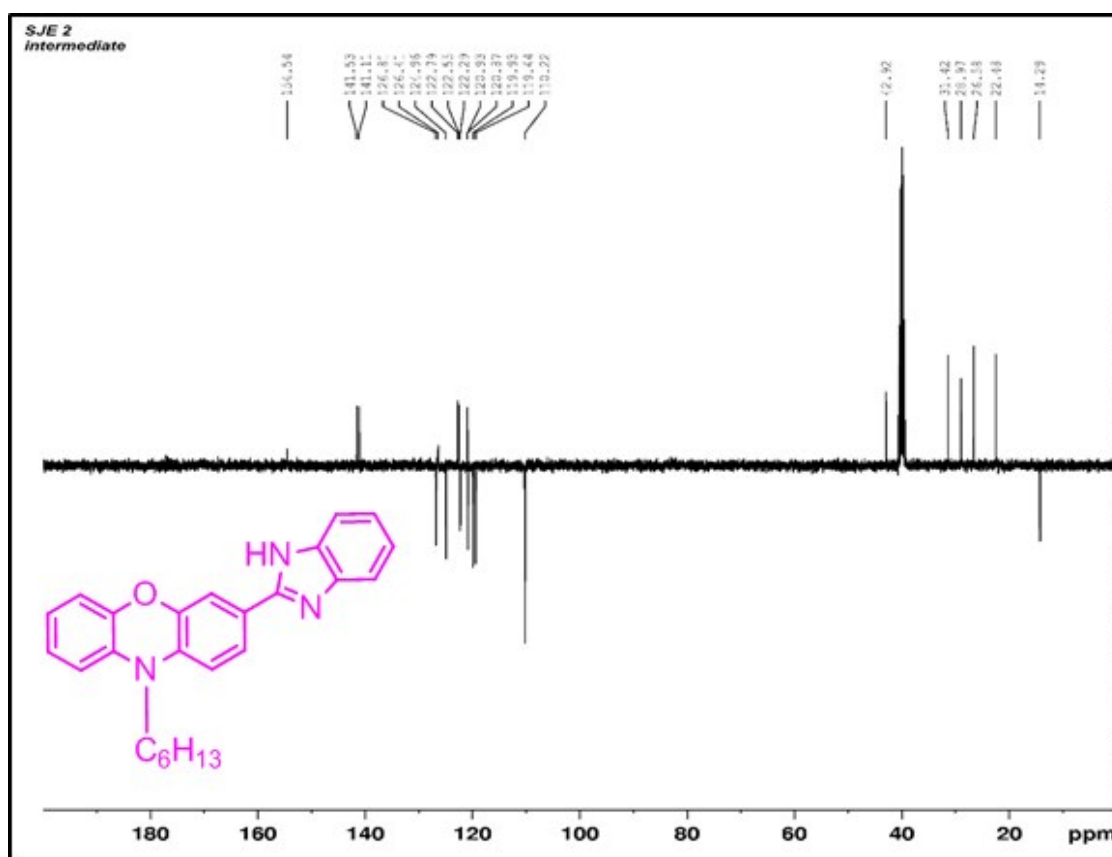
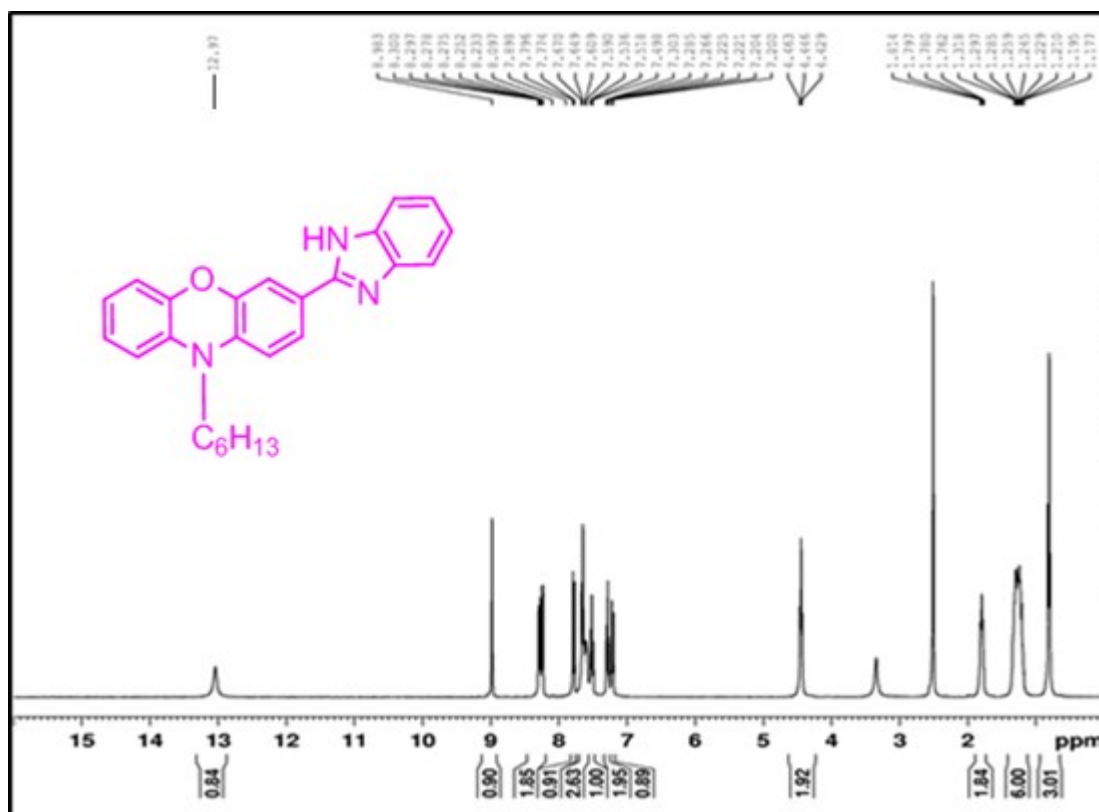


Fig. S6. ¹H-NMR and ¹³C-NMR and MS spectra of SJE 2 intermediate

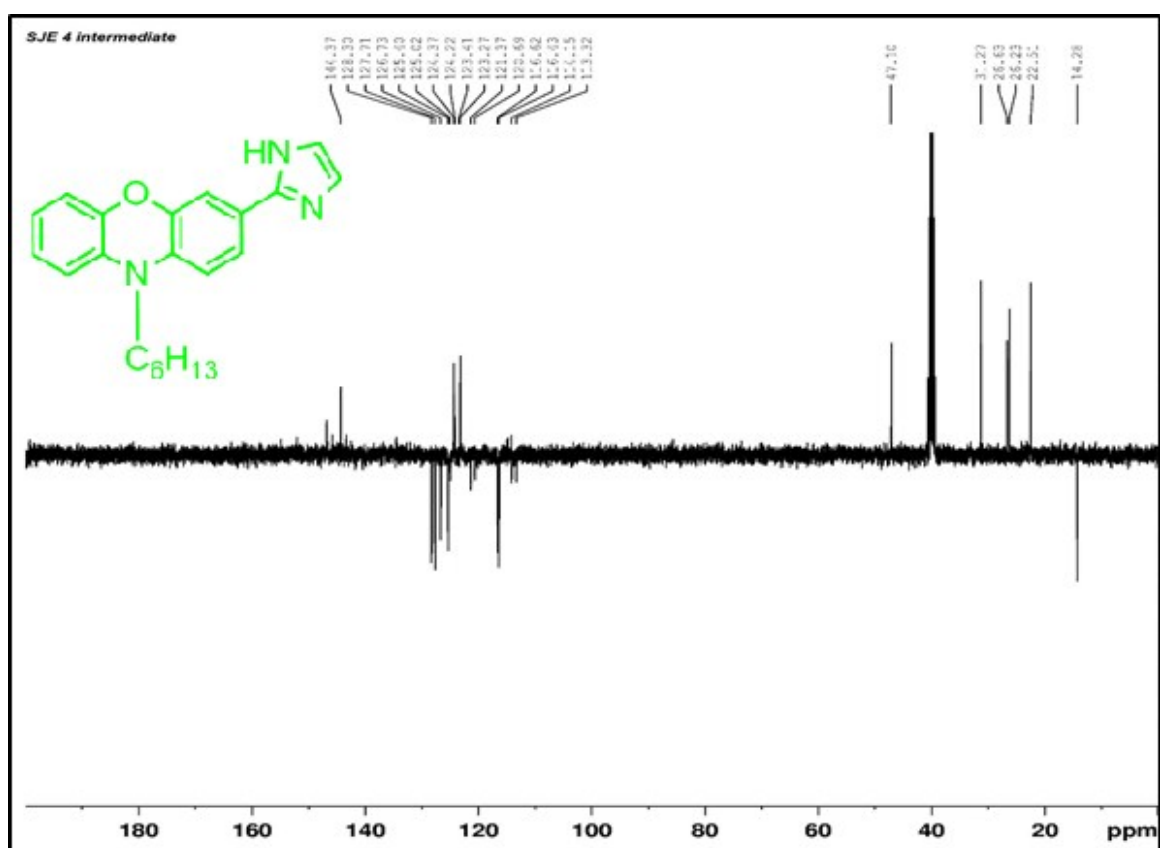
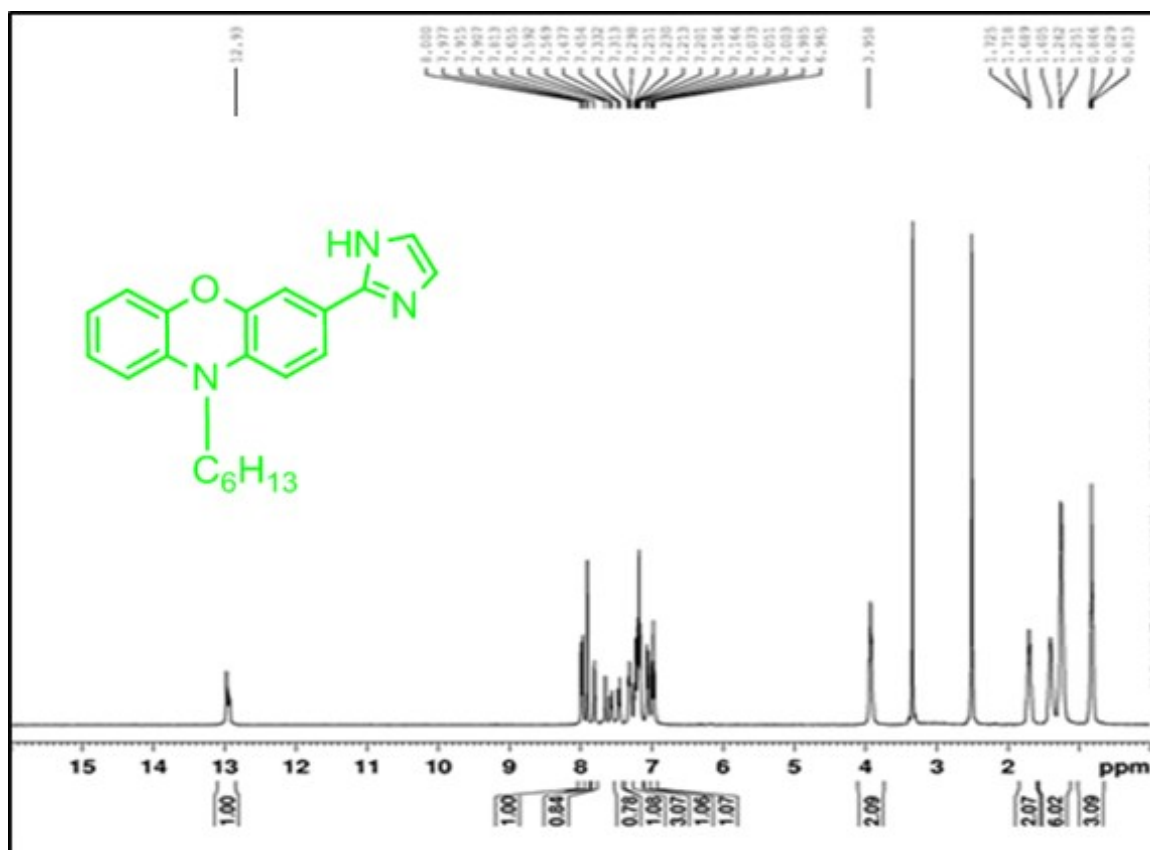


Fig. S7. ¹H-NMR and ¹³C-NMR and MS spectra of SJE 4 intermediate

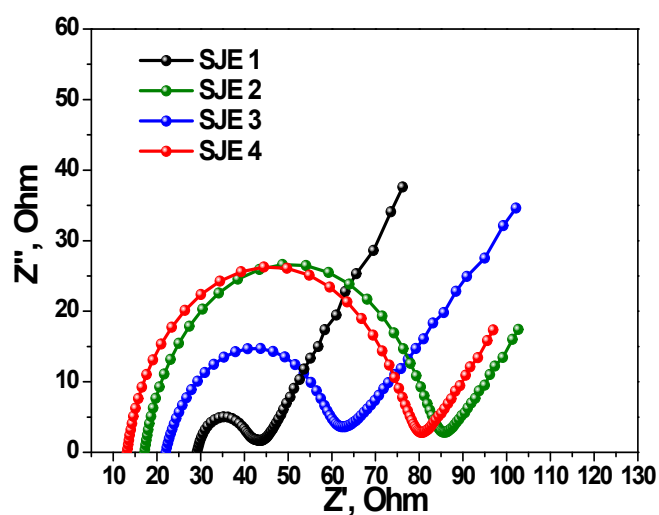


Fig. S8. EIS spectra of SJE 1- 4 between two platinum electrodes. The analysis were under frequency range 100MHz to 0.1Hz and an AC amplitude of 10mV. Conductivity was calculated from the R_b (Bulk resistance). The thickness of SOICs in between two symmetrical conducting plate, $L = 60\mu\text{m}$ and area, $A = 1.27\text{cm}^2$

| Electrolytes | R_b (Ω) | Conductivity σ (mS/cm) |
|--------------|--------------------|-------------------------------|
| SJE 1 | 29 | 1.62 |
| SJE 2 | 17 | 2.94 |
| SJE 3 | 22 | 2.13 |
| SJE 4 | 13 | 3.61 |

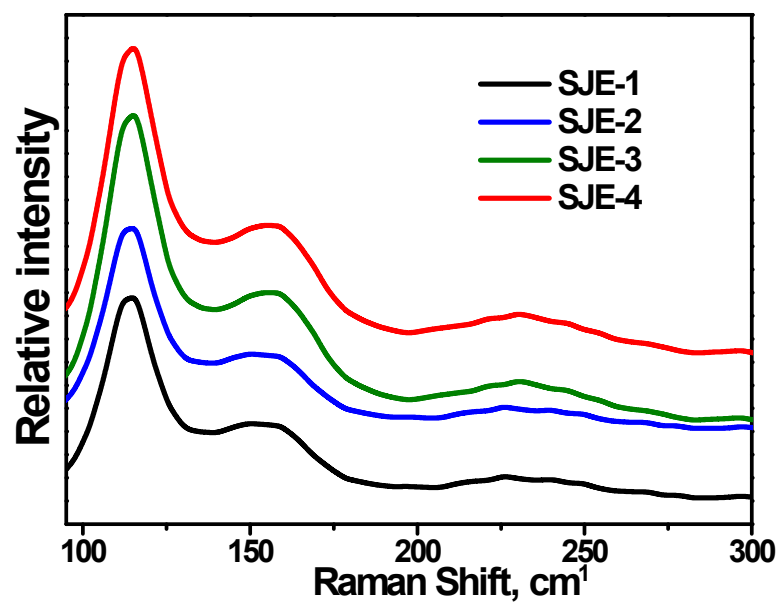


Fig. S9. Raman spectra of SJE 1- 4

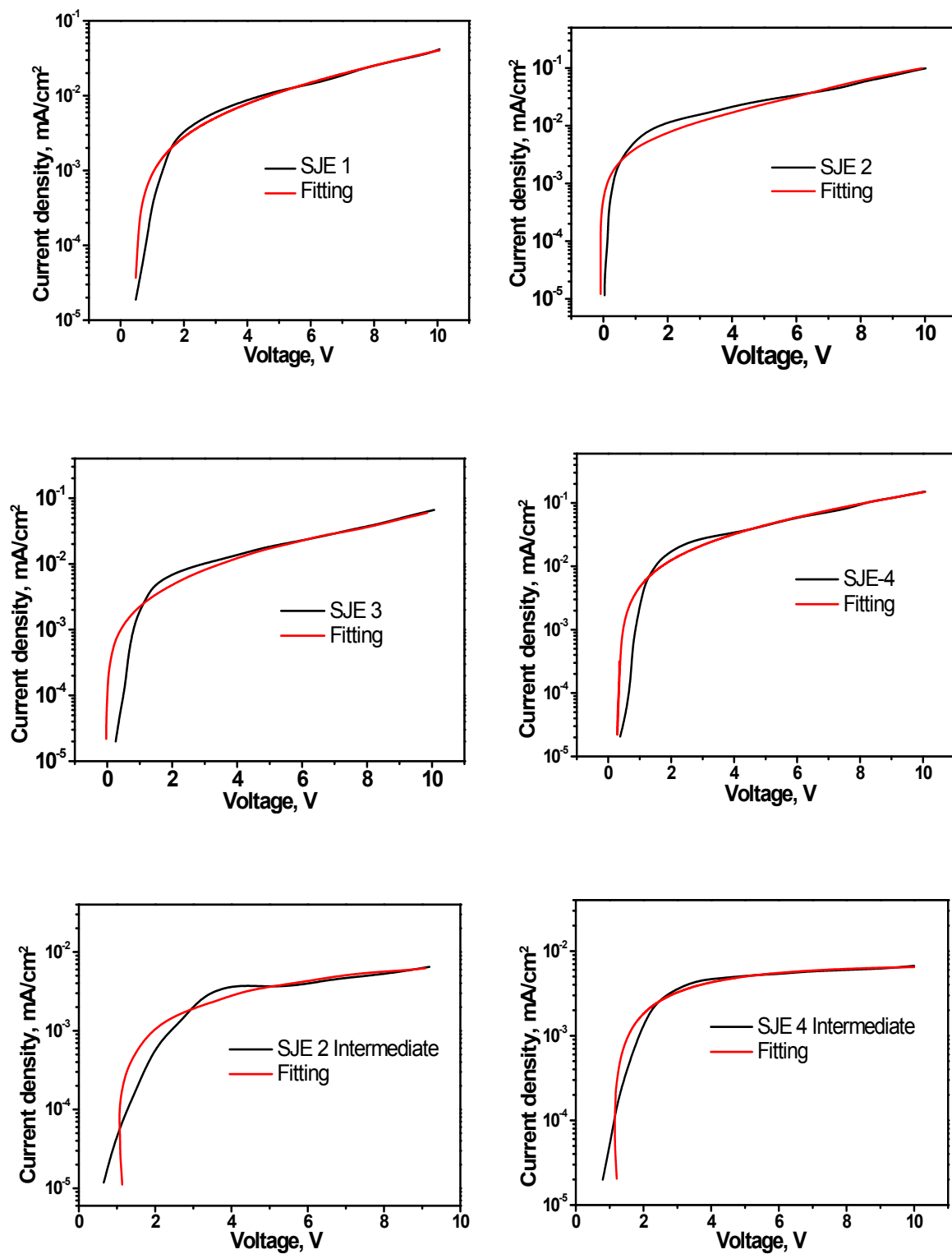


Fig. S10. J - V curve of hole only devices fabricated for determination of hole mobility

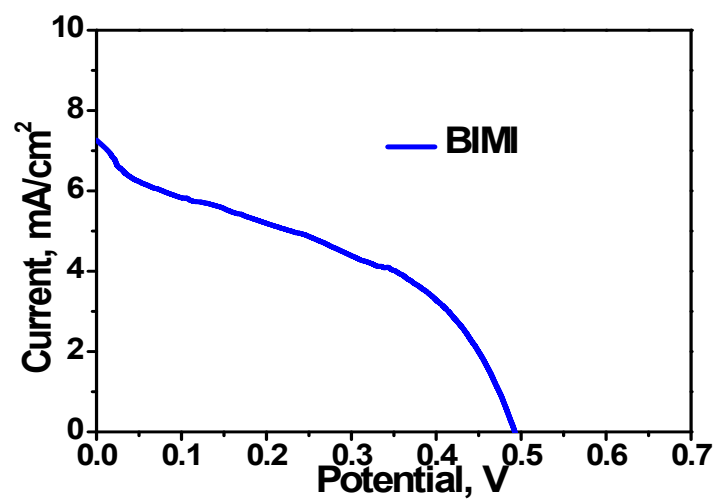


Fig. S11. J - V curve of BIMl electrolyte based device under simulated solar light AM1.5, 100mW/cm²

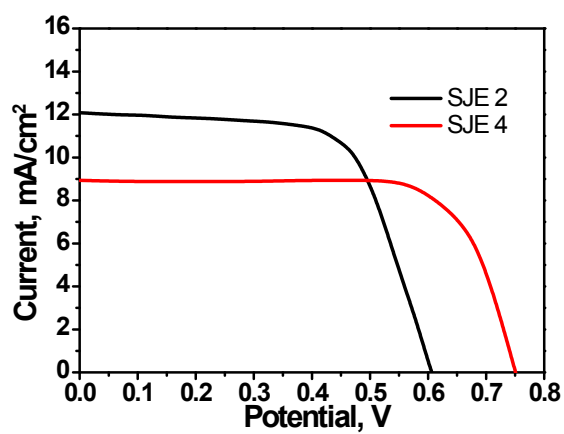


Fig. S12. J - V curve for ss-DSSC with 60µm spacer for SJE 2 and SJE 4

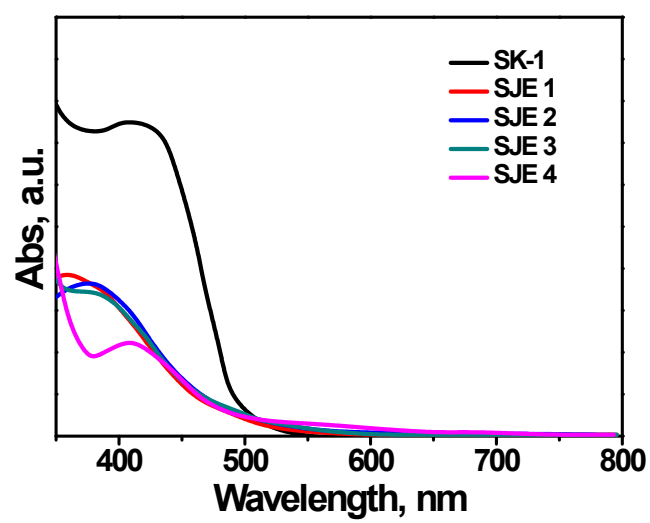


Fig. S13. UV-Vis spectra of pure SK 1 sensitizer and SJE 1-4

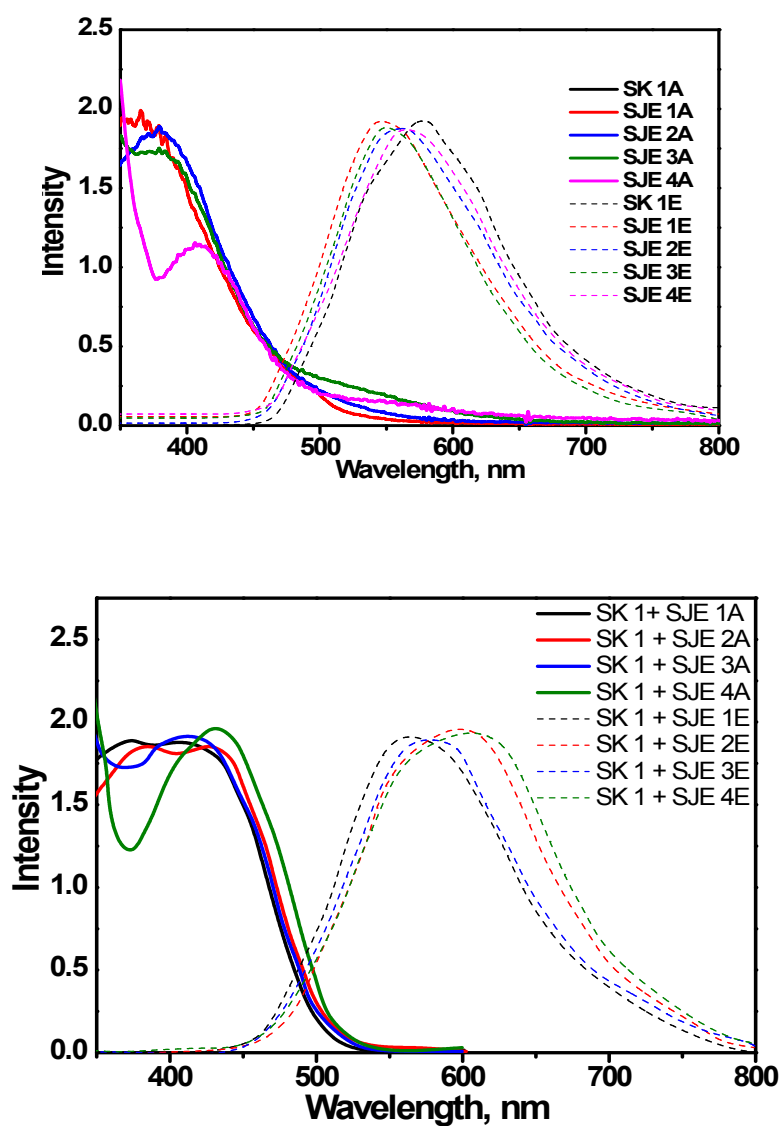


Fig. S14. UV-Vis and fluorescence spectra of SK 1 sensitizer and SJE 1-4

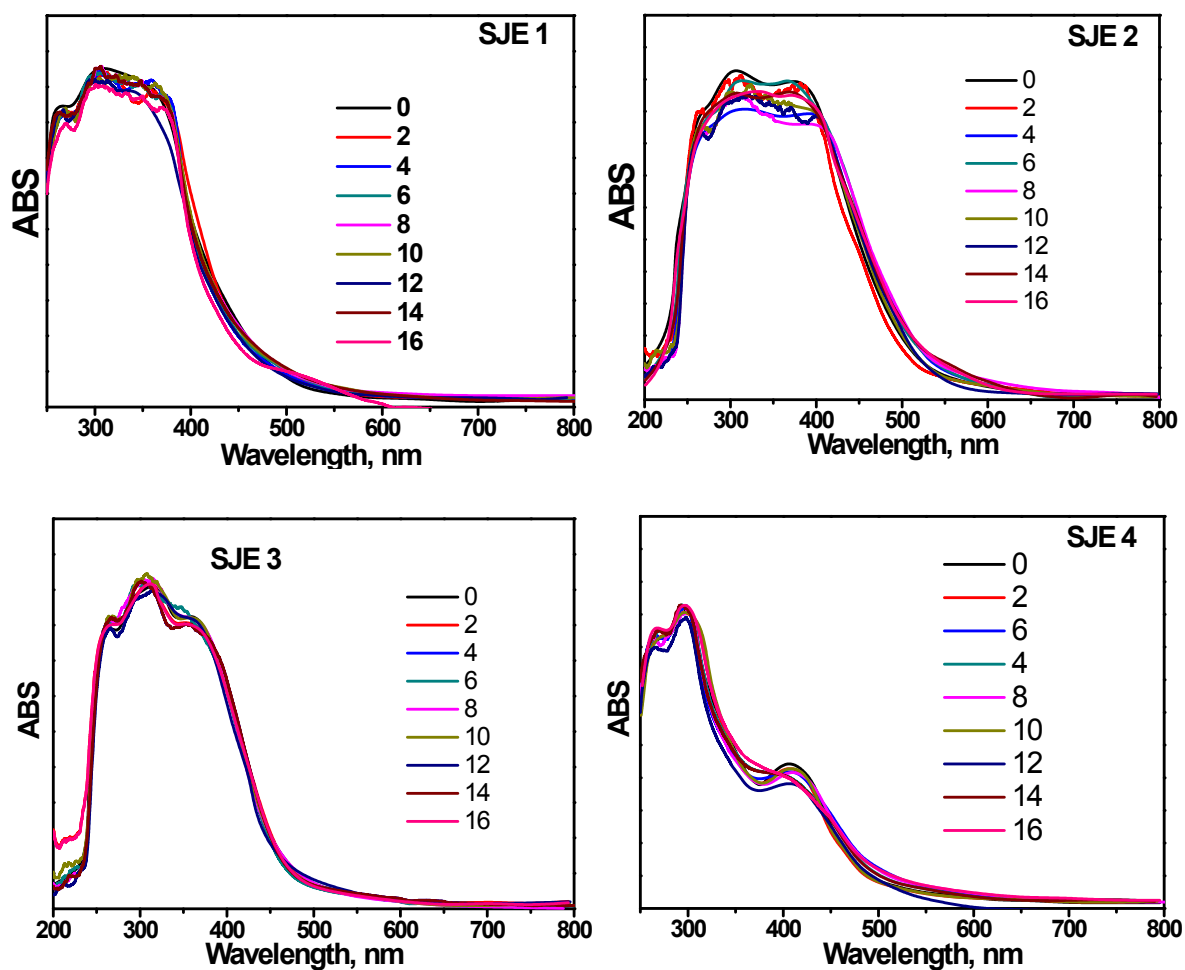
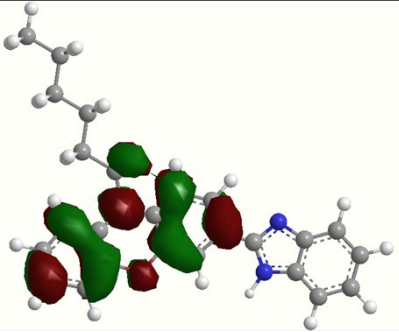
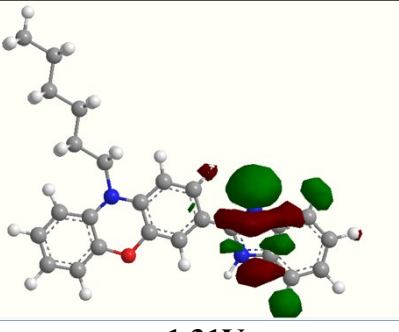
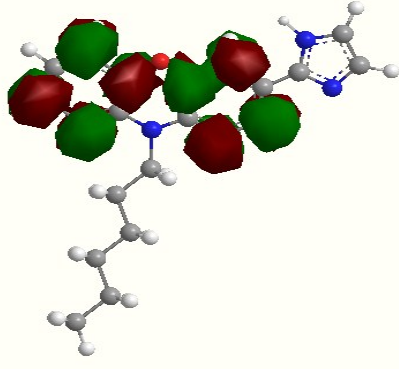
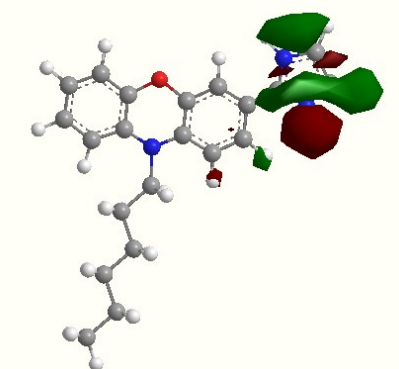


Fig. S15. Photostability study of SJE 1-4

We have carried out the UV-vis absorbance of all electrolytes in acetonitrile with different interval of sun light illumination from 0 to 16 days. There is no degradation observed in this compounds during this illumination. So, we can conclude that, these materials are highly stable and same is reflects in the device stability performance.

Table S1. HOMO-LUMO (DFT) calculation of SJE 2 and 4 intermediates

| Intermediate | HOMO | LUMO |
|--------------|---|---|
| SJE 2 |  1.18V |  -1.31V |
| SJE 4 |  1.22V |  -1.28V |

SJE intermediate HOMO-LUMO level shows by computational method. Gaussian, DFT calculations were carried out for optimization using the B3LYP functional with 6-31G(d p) basis set.